	Hits	Search Text	DBs
30	11	((pattern or hole or via or (line near6 space)) same (aspect near5	FPRS; EPO; JPO; DERWENT;
31	5		JPO; DERWENT;
32	0	((resist or photoresist) same (pattern or hole or via or opening) same (exposure or (irradiat\$4) or illumination) same (dimension or size)) and ((pattern or hole or via or (line near6 space)) same (aspect near5 ratio) same LSI) and ((resist near4 pattern) same (thicken\$4 or improv\$4 or enhanc\$4 or coat\$4 or top\$4coat\$4) same (heat\$4 or bak\$4))	USOCR

	Hits	Search Text	DBs
33	5	((resist or photoresist) same (pattern or hole or via or opening) same (exposure or (irradiat\$4) or illumination) same (dimension or size)) and ((pattern or hole or via or (line near6 space)) same (aspect near5 ratio) same LSI) and ((resist near4 pattern) same (thicken\$4 or improv\$4 or enhanc\$4 or coat\$4 or top\$4coat\$4 or smoothen\$5) same (heat\$4 or bak\$4))	· ·